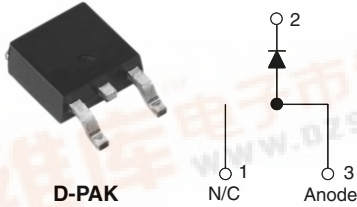




# HFA08SD60SPbF

Vishay High Power Products

## HEXFRED® Ultrafast Soft Recovery Diode, 8 A



### FEATURES

- Ultrafast recovery time
- Ultrasoft recovery
- Very low  $I_{RRM}$
- Very low  $Q_{rr}$
- Guaranteed avalanche
- Specified at operating conditions
- Lead (Pb)-free
- Designed and qualified for Q101 level



### BENEFITS

- Reduced RFI and EMI
- Reduced power loss in diode and switching transistor
- Higher frequency operation
- Reduced snubbing
- Reduced parts count

### DESCRIPTION

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for freewheeling, flyback, power converters, motor drives, and other applications where high speed and reduced switching losses are design requirements.

PRODUCT SUMMARY	
$V_R$	600 V
$V_F$ at 8 A at 25 °C	1.7 V
$I_{F(AV)}$	8 A
$t_{rr}$ (typical)	18 ns
$T_J$ (maximum)	150 °C

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	$V_{RRM}$		600	V
Maximum continuous forward current	$I_F$	$T_C = 100\text{ °C}$	8	A
Single pulse forward current	$I_{FSM}$		60	
Peak repetitive forward current	$I_{FRM}$		24	
Maximum power dissipation	$P_D$	$T_C = 100\text{ °C}$	14	W
Operating junction and storage temperature range	$T_J, T_{Stg}$		- 55 to + 150	°C

ELECTRICAL SPECIFICATIONS ( $T_J = 25\text{ °C}$ unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_R$	$I_R = 100\text{ }\mu\text{A}$		600	-	-	V
Forward voltage	$V_F$	$I_F = 8\text{ A}$	See fig. 1	-	1.4	1.7	
		$I_F = 16\text{ A}$		-	1.7	2.1	
		$I_F = 8\text{ A}, T_J = 125\text{ °C}$		-	1.4	1.7	
Maximum reverse leakage current	$I_R$	$V_R = V_R$ rated		-	0.3	5.0	$\mu\text{A}$
		$T_J = 125\text{ °C}, V_R = 0.8 \times V_R$ rated		-	100	500	
Junction capacitance	$C_T$	$V_R = 200\text{ V}$	See fig. 3	-	10	25	pF
Series inductance	$L_S$	Measured lead to lead 5 mm from package body		-	8.0	-	nH

\*Pb containing terminations are not RoHS compliant, exemptions may apply

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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	$t_{rr}$	$I_F = 1.0\text{ A}$ , $di_F/dt = 200\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$	-	18	-	ns
		$T_J = 25\text{ }^\circ\text{C}$	-	37	55	
		$T_J = 125\text{ }^\circ\text{C}$	-	55	90	
Peak recovery current	$I_{RRM}$	$T_J = 25\text{ }^\circ\text{C}$	-	3.5	5.0	A
		$T_J = 125\text{ }^\circ\text{C}$	-	4.5	8.0	
Reverse recovery charge	$Q_{rr}$	$T_J = 25\text{ }^\circ\text{C}$	-	65	138	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	124	360	
Rate of fall of recovery current	$di_{(rec)M}/dt$	$T_J = 25\text{ }^\circ\text{C}$	-	240	-	A/ $\mu\text{s}$
		$T_J = 125\text{ }^\circ\text{C}$	-	210	-	

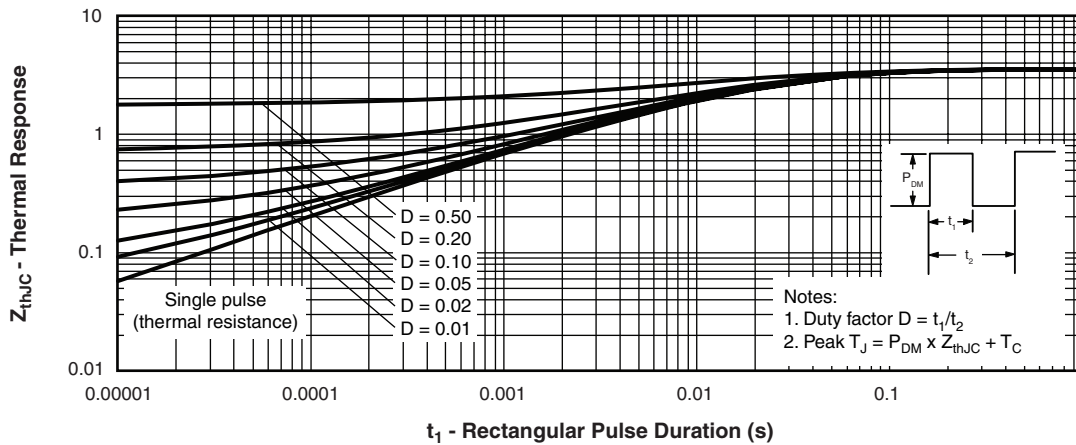
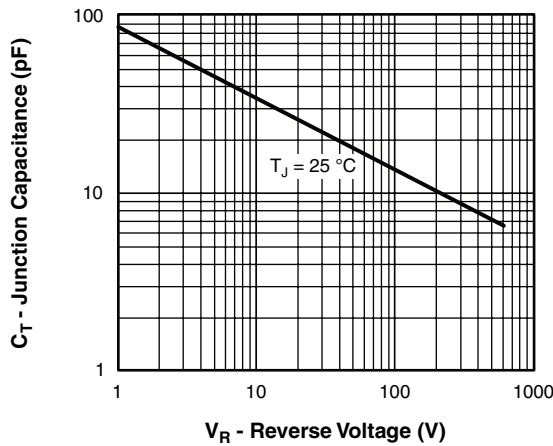
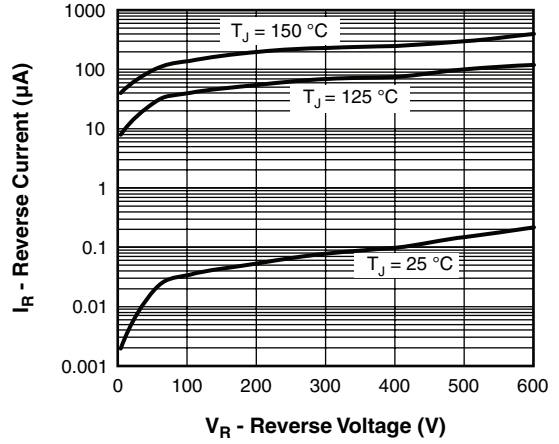
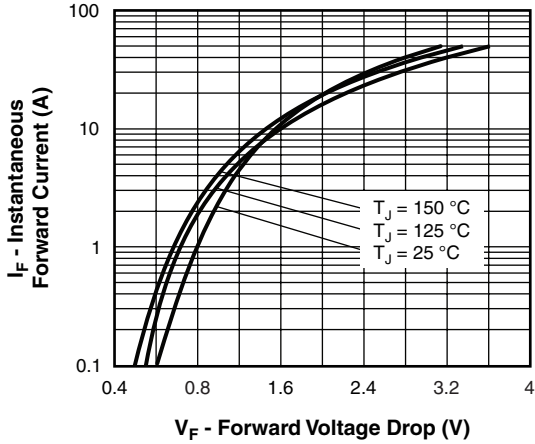
<b>THERMAL - MECHANICAL SPECIFICATIONS</b>						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	$T_J$ , $T_{Stg}$		- 55	-	150	$^\circ\text{C}$
Lead temperature	$T_{lead}$		-	-	300	
Thermal resistance, junction to case	$R_{thJC}$		-	-	3.5	$^\circ\text{C}/\text{W}$
Thermal resistance, junction to ambient	$R_{thJA}$	Typical socket mount	-	-	80	
Weight			-	2.0	-	g
			-	0.07	-	oz.
Marking device		Case style D-PAK	HFA08SD60S			



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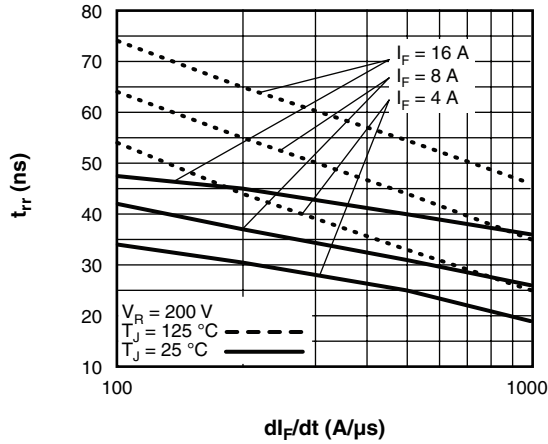


Fig. 5 - Typical Reverse Recovery Time vs.  $di_F/dt$

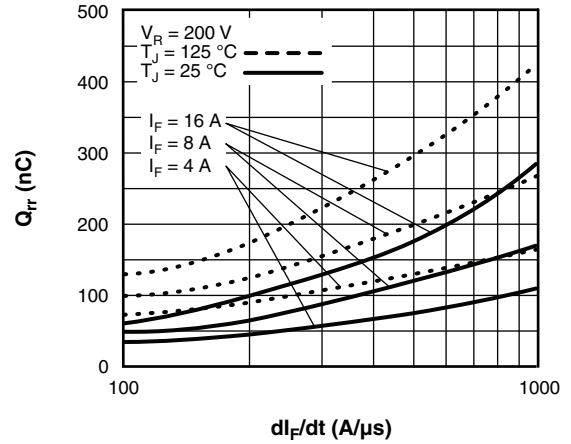


Fig. 7 - Typical Stored Charge vs.  $di_F/dt$

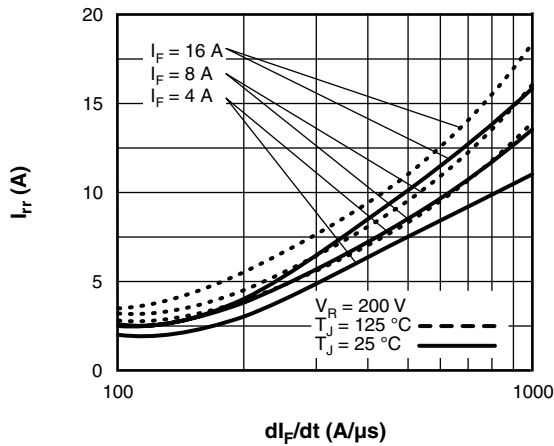


Fig. 6 - Typical Recovery Current vs.  $di_F/dt$

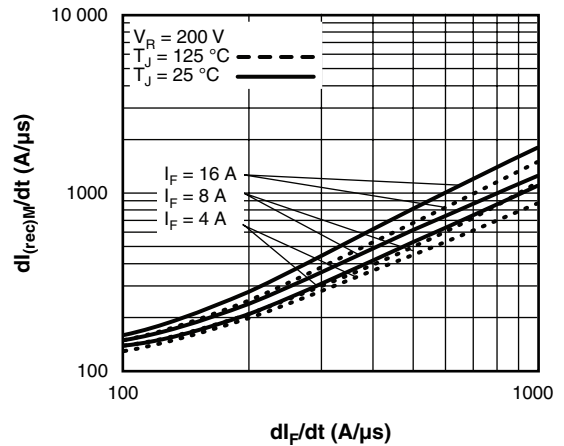


Fig. 8 - Typical  $dI_{(rec)M}/dt$  vs.  $di_F/dt$



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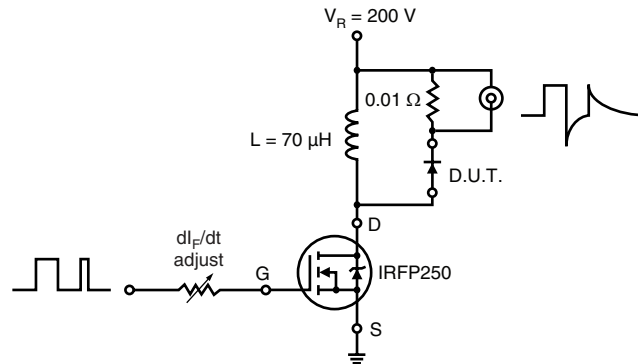
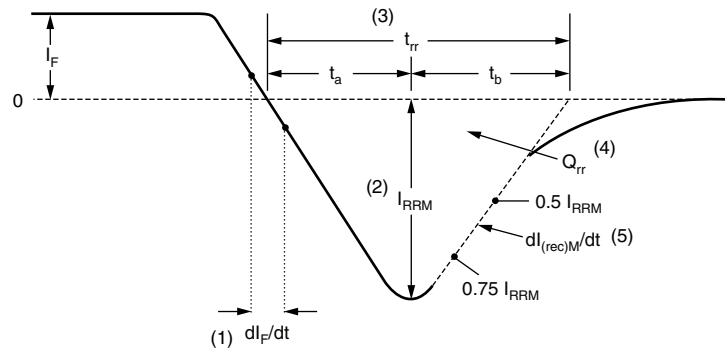


Fig. 9 - Reverse Recovery Parameter Test Circuit



(1)  $dI_F/dt$  - rate of change of current through zero crossing

(2)  $I_{RRM}$  - peak reverse recovery current

(3)  $t_{rr}$  - reverse recovery time measured from zero crossing point of negative going  $I_F$  to point where a line passing through  $0.75 I_{RRM}$  and  $0.50 I_{RRM}$  extrapolated to zero current.

(4)  $Q_{rr}$  - area under curve defined by  $t_{rr}$  and  $I_{RRM}$

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5)  $dI_{(rec)M}/dt$  - peak rate of change of current during  $t_b$  portion of  $t_{rr}$

Fig. 10 - Reverse Recovery Waveform and Definitions

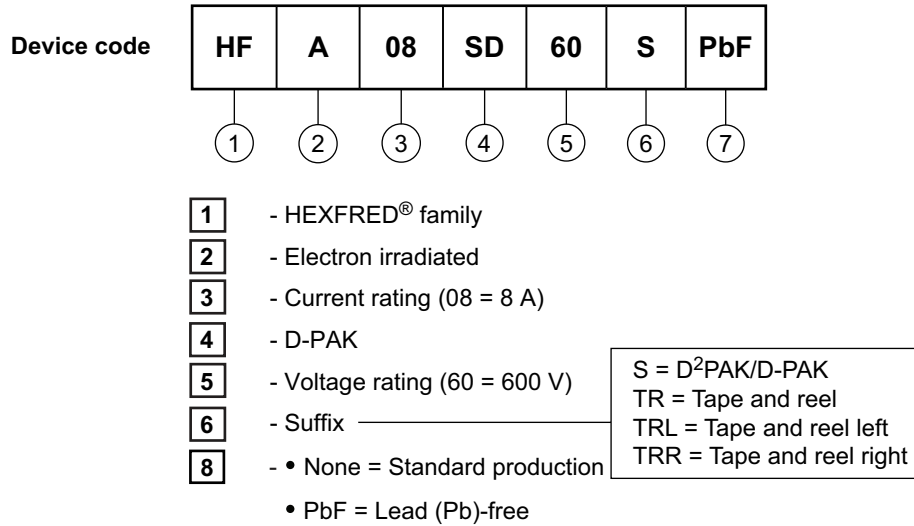
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## ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95016">http://www.vishay.com/doc?95016</a>
Part marking information	<a href="http://www.vishay.com/doc?95059">http://www.vishay.com/doc?95059</a>
Packaging information	<a href="http://www.vishay.com/doc?95033">http://www.vishay.com/doc?95033</a>



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